



BSS126SK

### N-CHANNEL DEPLETION MODE MOSFET

## **Product Summary**

BV <sub>DSX</sub>	Rds(on) max	I <sub>DSS</sub> min T <sub>A</sub> = +25°C
600V	700Ω @ V <sub>GS</sub> = 0V	7mA

### **Features and Benefits**

- N-Channel
- ESD Protected
- Depletion Mode
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

## **Description and Applications**

This new generation uses advanced planar technology MOSFET, provide excellent high voltage and fast switching, making it ideal for small-signal and level shift applications.

- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions





SOT23

Top View

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (c3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



Equivalent Circuit



Top View

### Ordering Information (Note 4)

Part Number	Case	Packaging
BSS126SK-7	SOT23	3000/Tape & Reel
BSS126SK-13	SOT23	10000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



K26 = Product Type Marking Code
YM = Date Code Marking
$\overline{Y}$ = Year (ex: H = 2020)

M = Month (ex: 9 = September)

Date Code Key												
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Н	I	J	K	L	М	N	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			VDSS	600	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 5) V <sub>GS</sub> = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	lo	30 24	mA
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	lo	35 28	mA
Continuous Source Current (Note 5) V <sub>GS</sub> = 10V	ls	30 24	mA		
Continuous Source Current (Note 6) $V_{GS}$ = 10V	ls	35 28	mA		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	Ідм	0.09	A		
Pulsed Source Current (10µs Pulse, Duty Cycle =	I <sub>SM</sub>	0.09	A		

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation, $@T_A = +25^{\circ}C$ (Note 5)	PD	1	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	Reja	124.7	°C/W
Power Dissipation, $@T_A = +25^{\circ}C$ (Note 6)	PD	1.3	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 6)	Reja	95.5	°C/W
Operating and Storage Temperature Range	TJ, T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)								
Drain-Source Breakdown Voltage	BV <sub>DSX</sub>	600	—	—	V	V <sub>GS</sub> = -5V, I <sub>D</sub> = 250µA		
Drain-Source Cutoff Current	ID(OFF)	_	_	0.1	μA	Vgs = -5V, Vds = 600V		
Gate-Source Leakage	Igss	_	_	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage	VGS(TH)	-2.7	-2.2	-1.4	V	$V_{DS} = 3V$ , $I_D = 8\mu A$		
On-State Drain Current	IDSS	7	_	_	mA	$V_{GS} = 0V, V_{DS} = 25V$		
Static Drain-Source On-Resistance	Proven		111	500	Ω	$V_{GS} = 10V, I_D = 16mA$		
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		101	700	12	$V_{GS} = 0V, I_D = 3mA$		
Diode Forward Voltage	Vsd		0.7	1.3	V	V <sub>GS</sub> = -5V, I <sub>S</sub> = 16mA		
DYNAMIC CHARACTERISTICS (Note 8)								
Input Capacitance	Ciss	_	30.9	—		V <sub>GS</sub> = -5V, V <sub>DS</sub> = 25V, f = 1MHz		
Output Capacitance	Coss		4.2	_	pF			
Reverse Transfer Capacitance	Crss		0.8	_				
Gate Resistance	R <sub>G</sub>		121	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$		
Total Gate Charge	Qg	_	2	_		$V_{DD} = 400 V,$		
Gate-Source Charge	Qgs	_	0.03	_	nC	$I_D = 10 m A$ ,		
Gate-Drain Charge	Qgd	_	1.7	_		$V_{GS} = -3V$ to $5V$		
Turn-On Delay Time	tD(ON)	_	5.2	_	ns	N/ 000N/		
Turn-On Rise Time	t <sub>R</sub>	_	17	_	ns	$-V_{DD} = 300V,$		
Turn-Off Delay Time	tD(OFF)		67	_	ns	$V_{GS} = -3V \text{ to } 7V,$		
Turn-Off Fall Time	tF	_	873	_	ns	$I_D = 0.01A, R_G = 6\Omega$		
Reverse Recovery Time	t <sub>RR</sub>		164	_	ns	$V_R = -100V, I_F = -1A, V_{GS} = -5V$		
Reverse Recovery Charge	Qrr	_	382	_	nC	di/dt = 100A/µs		

Notes: 5. Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.

6. Device mounted on  $1" \times 1"$  FR-4 PCB with high coverage 2 oz. Copper, single sided.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.





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## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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